

Ultra Low Noise, High IP3

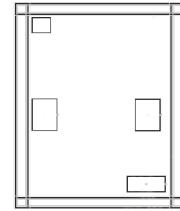
Monolithic Amplifier Die

PMA2-33LN-D+

50Ω 0.4 to 3.0 GHz

The Big Deal

- Ultra Low Noise Figure, 0.47 dB
- High Gain, High IP3



Product Overview

Mini-Circuits PMA2-33LN-D+ is an E-PHEMT based, ultra-low noise MMIC amplifier die with a unique combination of low noise and high IP3, making this amplifier ideal for sensitive, high-dynamic range receiver applications. This design operates on a single 3V supply, is well matched for 50Ω systems.

Key Features

Feature	Advantages
Ultra Low Noise, 0.47 dB at 0.9 GHz	Enables lower system noise figure performance.
High IP3, • +33.8 dBm at 0.9 GHz and • +38.5 dBm at 3 GHz	Combination of low noise and high IP3 makes this MMIC amplifier ideal for use in low noise receiver front end (RFE) as it gives the user advantages of sensitivity & two-tone IM performance at both ends of the dynamic range.
Low operating voltage, 3V	Achieves high IP3 using lower voltage compared to other devices of its kind.
Max input power • 27 dBm (5 minutes) • 14 to +22 dBm (Continuous)	Ruggedized design provides high power handling for input powers common at receiver inputs, eliminating the need for an external limiter in most cases
High reliability	Low signal operating current of 56 mA nominal maintains junction temperatures typically below 93°C at 85°C ground lead temperature.

Ultra Low Noise, High IP3

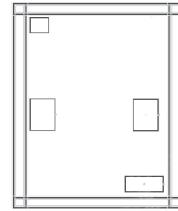
Monolithic Amplifier Die

PMA2-33LN-D+

50Ω 0.4 to 3.0 GHz

Product Features

- Ultra Low Noise figure, 0.47 dB at 0.9 GHz
- High IP3, 34 dBm typ. at 0.9 GHz, +39 dBm at 3 GHz
- High Pout, P1dB 17.6 dBm typ. at 0.9 GHz



Typical Applications

- Base station infrastructure
- Portable Wireless
- LTE
- GPS
- GSM
- Airborne radar

+RoHS Compliant

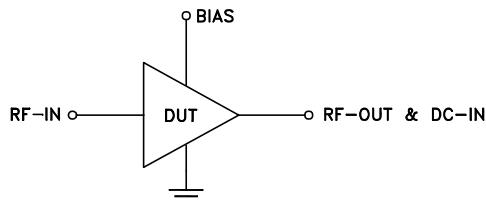
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

Ordering Information: Refer to Last Page

General Description

The PMA2-33LN-D+ (RoHS compliant) amplifier die is fabricated using 0.25 µm E-PHEMT technology and offers extremely high dynamic range with ultra low noise figure and good input and output return loss.

Simplified Schematic and Pad description



Pad Function	Description (See Figure 1)
RF-IN	Connects to RF input via C1 and Bias Pad via L1
RF-OUT & DC-IN	Connects to RF out via C2 and V _s via L2 & R2
Bias	Connects to Supply voltage (V _s) via R1 & Rb
Ground	Connects to ground

Note: 1. Bond Pad material - Gold
2. Bottom of Die - Gold plated

Electrical Specifications¹ at 25°C and 3V, unless noted

Parameter	Condition (GHz)	Min.	Typ.	Max.	Units
Frequency range		0.4		3.0	GHz
Noise figure	0.4 0.9 1.5 2.0 3.0		0.56 0.47 0.55 0.53 0.79		dB
Gain	0.4 0.9 1.5 2.0 3.0		23.7 18.4 14.2 11.8 8.4		dB
Input return loss	0.4 0.9 1.5 2.0 3.0		10.5 13.7 15.6 16.5 17.5		dB
Output return loss	0.4 0.9 1.5 2.0 3.0		17.4 29.3 24.5 22.8 23.6		dB
Output power @ 1dB compression	0.4 0.9 1.5 2.0 3.0		17.0 17.6 18.1 18.0 18.6		dBm
Output IP3	0.4 0.9 1.5 2.0 3.0		30.5 33.8 35.3 35.4 38.5		dBm
Device operating voltage			3.0		V
Device operating current at 3V ²		—	58	67	mA
Device current variation vs voltage at 25°C			0.025		mA/mV
Thermal resistance, junction-to-ground lead			54		°C/W

1. Measured on Mini-Circuits Die Characterization test board. See Characterization Test Circuit (Fig. 1)

2. Current increases at P1dB

Absolute Maximum Ratings^{3,4}

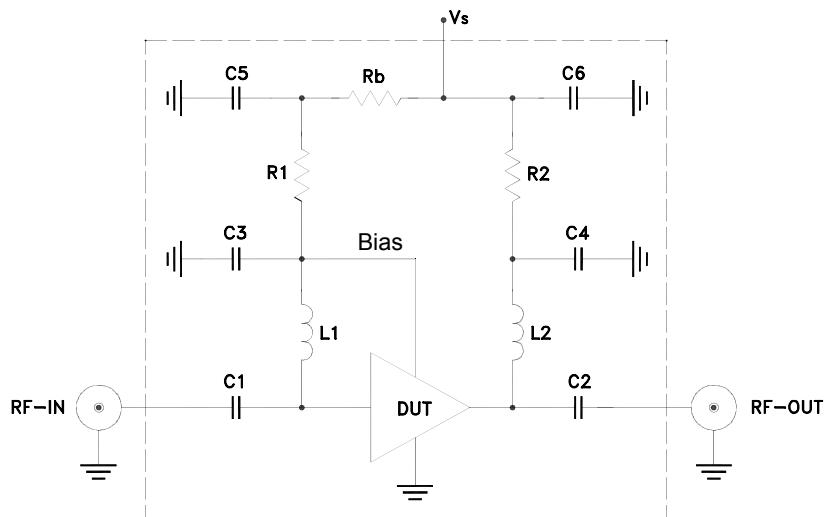
Parameter	Ratings
Operating Temperature (ground lead)	-40°C to 85°C
Junction Temperature	150°C
Total Power Dissipation	0.5 W
Input Power (CW), Vd=3V	+27dBm (5minutes max) +14 dBm to 1.5 GHz and +22 dBm over 1.5 to 3 GHz (continuos)
DC Voltage	5.5 V

3. Permanent damage may occur if any of these limits are exceeded.

Electrical maximum ratings are not intended for continuous normal operation.

4. Die performance measured in industry standard 2x2mm 8-lead package.



Recommended Application and Characterization Test Circuit

Component	Value	Size
C1, C2	100pF	0402
C3, C6	4.7μF	0402
C4	33pF	0402
C5	Not Used	—
L1, L2	33nH	0402
R1	0Ω	0402
R2	10Ω	0603
Rb	4.02kΩ	0402

Fig 1. Application and Characterization circuit

Note: This block diagram is used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-736+)

Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return loss: Pin= -25dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/tone at output.

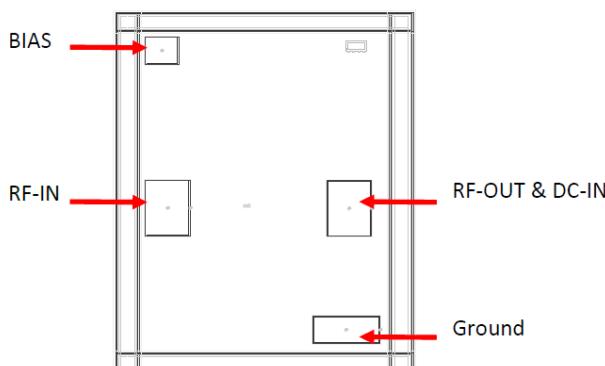
Die Layout

Fig 2. Die Layout

Critical Dimensions

Parameter	Values
Die Thickness, μm	100
Die Width, μm	600
Die Length, μm	900
Bond Pad Size (RF-IN, RF-OUT & DC-IN), μm	150 x 150
Bond Pad Size (Bias), μm	75 x 75
Bond Pad Size (Ground pad), μm	150 x 75

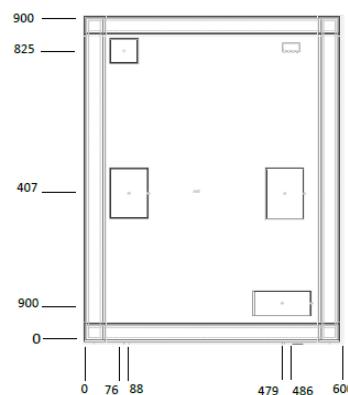
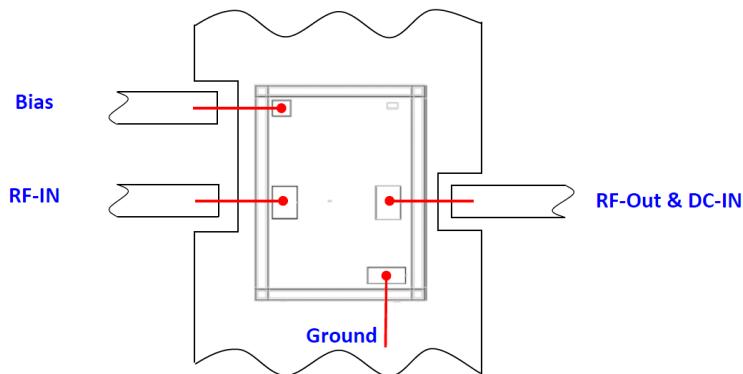
Bonding Pad Position
(Dimensions in μm, Typical)

Fig 3. Bonding Pad Positions

Assembly and Handling Procedure

1. Storage
Dice should be stored in a dry nitrogen purged desiccators or equivalent.
2. ESD
MMIC EPHEMPT amplifier dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static workstation. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.
3. Die Attach
The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030HK-PT/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.
4. Wire Bonding
Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as reasonable to minimize performance degradation due to undesirable series inductance.

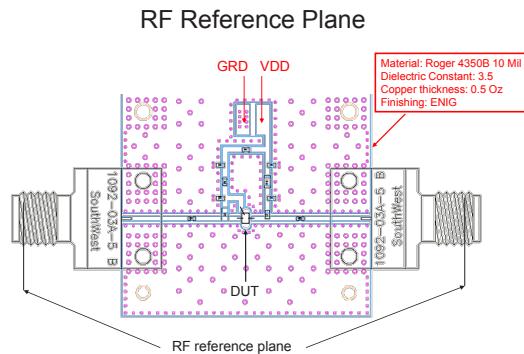
Assembly Diagram



Recommended Wire Length, Typical

Wire	Wire Length (mm)	Wire Loop Height (mm)
RF-IN, Bias	0.80	0.15
RF-OUT & DC-IN	1.00	0.15
GROUND	0.90	0.15

RF Reference Plane - No port extension



Additional Detailed Technical Information <i>additional information is available on our dash board.</i>		
Performance Data	Data Table	
	Swept Graphs	
	S-Parameter (S2P Files) Data Set with and without port extension(.zip file)	
Case Style	Die	
Die Ordering and packaging information	Quantity, Package Small, Gel - Pak: 10,50,100 KGD* Medium [†] , Partial wafer: KGD*<2090 Large [†] , Full Wafer	Model No. PMA2-33LN-DG+ PMA2-33LN-DP+ PMA2-33LN-DF+
	[†] Available upon request contact sales representative	
	Refer to AN-60-067	
Environmental Ratings	ENV-80	

*Known Good Dice ("KGD") means that the dice in question have been subjected to Mini-Circuits DC test performance criteria and measurement instructions and that the parametric data of such dice fall within a predefined range. While DC testing is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

ESD Rating**

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

** Tested in industry standard 2x2mm, 8-lead plastic package.

Additional Notes

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*Typical Performance Data***Definitions:**

Input Return Loss = -S11 (dB)

Gain(Power Gain) = S21 (dB)

Reverse Isolation = -S12 (dB)

Output Return Loss = -S22 (dB)

TEST CONDITIONS: Vd = 3V, Id = 58mA @Temperature = +25°C

FREQ. (MHz)	Gain (dB)	Isolation (dB)	Input Return Loss (dB)	Output Return Loss (dB)	Stability		IP-3 Output (dBm)	1dB Comp. Output (dBm)	Noise Figure (dB)
					K	Measure			
400	23.69	28.12	10.53	17.89	1.08	0.66	33.08	16.99	0.56
450	23.15	27.05	11.42	19.85	1.07	0.62	33.36	17.04	0.54
500	22.57	26.25	12.06	21.72	1.06	0.60	33.44	17.59	0.52
550	21.99	25.52	12.54	23.53	1.05	0.59	33.92	17.37	0.51
600	21.43	24.81	12.87	25.03	1.05	0.57	34.15	17.39	0.50
650	20.88	24.18	13.15	26.45	1.05	0.57	34.34	17.74	0.50
700	20.35	23.62	13.40	27.89	1.04	0.56	34.37	17.53	0.49
750	19.84	23.09	13.64	29.37	1.04	0.56	34.76	17.58	0.49
800	19.35	22.57	13.84	30.57	1.04	0.56	35.23	17.92	0.49
850	18.88	22.11	14.02	31.28	1.04	0.56	35.55	17.72	0.48
900	18.44	21.64	14.26	31.60	1.04	0.56	36.09	17.61	0.47
950	18.01	21.25	14.46	31.79	1.05	0.56	36.77	17.65	0.46
1000	17.60	20.83	14.66	31.67	1.05	0.56	36.61	17.37	0.46
1050	17.21	20.44	14.86	31.49	1.05	0.56	36.41	17.72	0.46
1100	16.84	20.06	15.13	30.92	1.05	0.55	36.94	17.37	0.47
1150	16.48	19.71	15.34	30.20	1.05	0.55	36.59	17.44	0.48
1200	16.14	19.35	15.60	29.60	1.05	0.55	36.63	18.05	0.50
1300	15.49	18.72	16.01	28.20	1.05	0.55	36.98	17.68	0.52
1400	14.88	18.12	16.53	27.25	1.05	0.55	37.92	17.83	0.54
1500	14.32	17.57	16.99	26.35	1.05	0.55	37.54	18.12	0.55
1600	13.79	17.05	17.47	25.86	1.05	0.55	38.01	17.69	0.54
1700	13.29	16.57	17.86	25.50	1.05	0.55	38.16	17.53	0.53
1800	12.81	16.11	18.31	25.28	1.06	0.55	38.60	17.83	0.53
1900	12.36	15.70	18.62	25.17	1.06	0.55	38.01	18.47	0.52
2000	11.95	15.29	18.79	25.05	1.06	0.55	38.09	18.01	0.52
2100	11.55	14.89	18.96	25.08	1.06	0.55	38.32	18.32	0.51
2200	11.17	14.53	18.94	25.40	1.06	0.56	38.03	18.41	0.51
2300	10.80	14.19	18.91	25.79	1.06	0.56	37.99	18.24	0.52
2400	10.43	13.87	18.96	25.88	1.06	0.56	37.77	18.03	0.53
2500	10.08	13.58	18.90	26.13	1.07	0.57	37.65	18.03	0.58
2600	9.73	13.30	19.01	25.95	1.07	0.58	39.04	18.49	0.65
2700	9.38	13.06	19.11	26.01	1.07	0.59	38.00	18.26	0.74
2800	9.05	12.82	19.41	25.33	1.08	0.60	39.15	18.49	0.79
2900	8.75	12.58	19.68	24.74	1.08	0.60	40.43	18.54	0.81
3000	8.48	12.33	19.95	23.63	1.08	0.60	40.23	18.60	0.79
3100	8.24	12.06	19.97	22.61	1.08	0.60	41.40	18.42	0.77
3200	8.01	11.79	19.93	21.67	1.07	0.59	41.98	18.31	0.76
3300	7.79	11.55	19.85	20.90	1.07	0.59	42.74	18.97	0.78
3400	7.56	11.33	19.68	20.11	1.07	0.59	42.87	19.11	0.80
3500	7.34	11.11	19.55	19.50	1.07	0.59	42.21	19.01	0.83

MMIC Amplifier Die

PMA2-33LN-D+

Typical Performance Data

Definitions:

Input Return Loss = -S11 (dB)

Gain(Power Gain) = S21 (dB)

Reverse Isolation = -S12 (dB)

Output Return Loss = -S22 (dB)

TEST CONDITIONS: Vd = 2.70V, Id = 50mA @Temperature = +25°C

FREQ. (MHz)	Gain (dB)	Isolation (dB)	Input Return Loss (dB)	Output Return Loss (dB)	Stability		IP-3 Output (dBm)	1dB Comp. Output (dBm)	Noise Figure (dB)
400	23.58	27.90	10.11	18.29	1.07	0.67	31.48	16.22	0.60
450	23.05	27.00	10.99	20.39	1.06	0.63	32.48	16.26	0.58
500	22.48	26.13	11.63	22.47	1.05	0.61	33.12	16.82	0.56
550	21.90	25.40	12.12	24.50	1.05	0.59	33.89	16.60	0.55
600	21.33	24.73	12.48	26.20	1.04	0.58	33.79	16.62	0.54
650	20.79	24.11	12.76	27.81	1.04	0.58	34.22	16.96	0.54
700	20.26	23.54	13.01	29.45	1.04	0.57	34.55	16.76	0.53
750	19.75	23.04	13.26	31.08	1.04	0.57	35.01	16.81	0.53
800	19.26	22.54	13.48	32.37	1.04	0.57	35.41	17.16	0.52
850	18.79	22.07	13.67	33.09	1.04	0.57	35.75	16.96	0.51
900	18.35	21.62	13.90	33.18	1.04	0.57	36.00	16.95	0.50
950	17.92	21.20	14.11	33.22	1.04	0.57	35.89	16.90	0.49
1000	17.52	20.80	14.32	32.95	1.05	0.57	36.37	16.64	0.48
1050	17.12	20.41	14.51	32.46	1.05	0.57	36.55	16.99	0.49
1100	16.75	20.04	14.78	31.65	1.05	0.57	36.66	16.72	0.51
1150	16.40	19.70	15.01	30.77	1.05	0.57	36.36	16.81	0.51
1200	16.05	19.36	15.24	30.07	1.05	0.57	36.45	17.40	0.51
1300	15.40	18.69	15.67	28.61	1.05	0.56	36.49	16.98	0.52
1400	14.80	18.12	16.17	27.51	1.05	0.56	36.46	17.11	0.55
1500	14.23	17.56	16.60	26.57	1.05	0.56	36.95	17.47	0.58
1600	13.71	17.04	17.07	26.10	1.05	0.56	37.09	17.09	0.59
1700	13.21	16.56	17.45	25.70	1.06	0.56	37.34	16.91	0.59
1800	12.73	16.11	17.89	25.57	1.06	0.56	36.66	17.20	0.59
1900	12.28	15.68	18.19	25.36	1.06	0.56	36.77	17.77	0.57
2000	11.87	15.25	18.37	25.23	1.06	0.56	36.85	17.40	0.56
2100	11.48	14.89	18.55	25.26	1.06	0.56	37.49	17.62	0.55
2200	11.09	14.52	18.54	25.55	1.06	0.56	37.49	17.71	0.55
2300	10.72	14.18	18.51	25.88	1.06	0.57	39.25	17.66	0.56
2400	10.36	13.86	18.57	25.93	1.06	0.57	38.88	17.44	0.56
2500	10.00	13.57	18.52	26.14	1.07	0.58	39.37	17.45	0.61
2600	9.65	13.31	18.60	25.95	1.07	0.59	38.27	17.90	0.67
2700	9.30	13.05	18.73	25.97	1.08	0.60	37.33	17.68	0.77
2800	8.98	12.81	19.01	25.30	1.08	0.60	40.20	17.88	0.81
2900	8.68	12.57	19.29	24.78	1.08	0.61	38.00	17.96	0.84
3000	8.41	12.31	19.54	23.69	1.08	0.61	40.05	17.92	0.82
3100	8.17	12.04	19.55	22.69	1.08	0.61	40.42	17.81	0.81
3200	7.95	11.79	19.53	21.66	1.08	0.60	40.70	17.72	0.83
3300	7.72	11.55	19.48	20.93	1.07	0.60	39.29	18.26	0.83
3400	7.50	11.31	19.31	20.14	1.07	0.60	38.98	18.38	0.86
3500	7.27	11.10	19.22	19.57	1.07	0.60	39.09	18.15	0.86

MMIC Amplifier Die

PMA2-33LN-D+

Typical Performance Data

Definitions:

Input Return Loss = -S11 (dB)

Gain(Power Gain) = S21 (dB)

Reverse Isolation = -S12 (dB)

Output Return Loss = -S22 (dB)

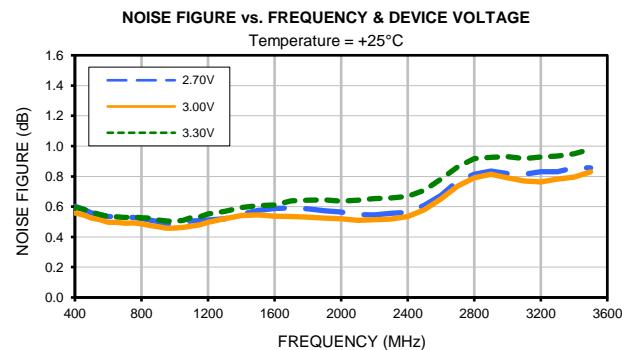
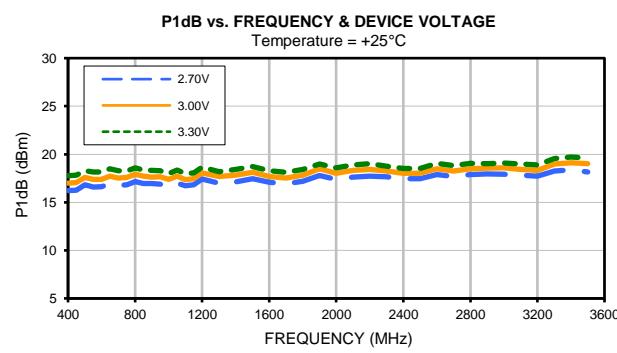
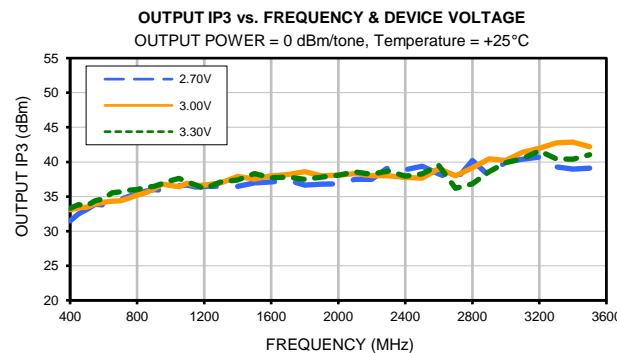
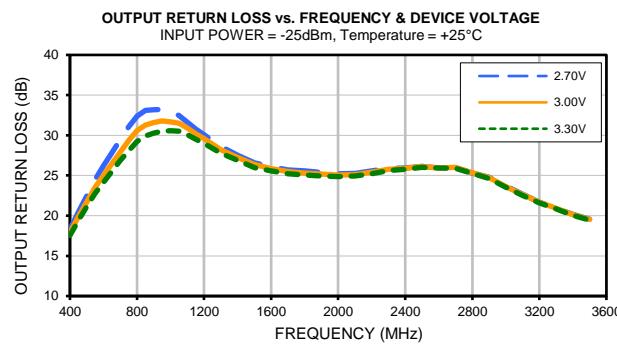
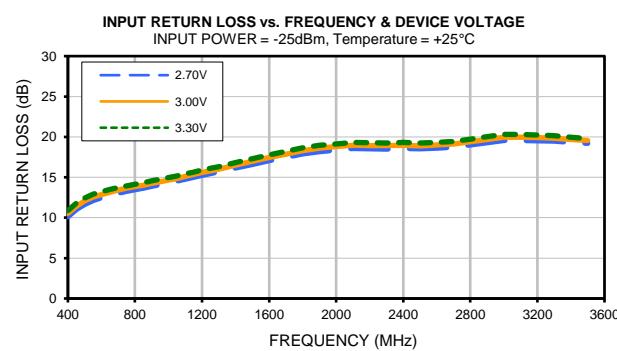
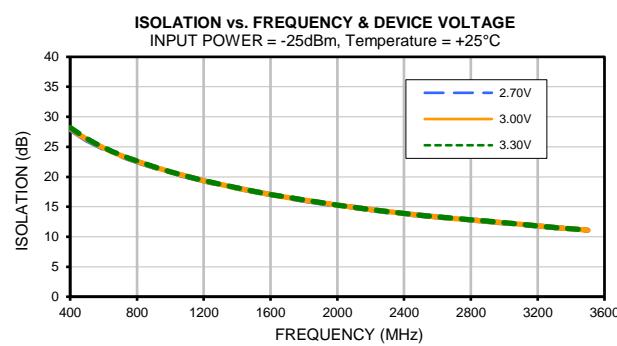
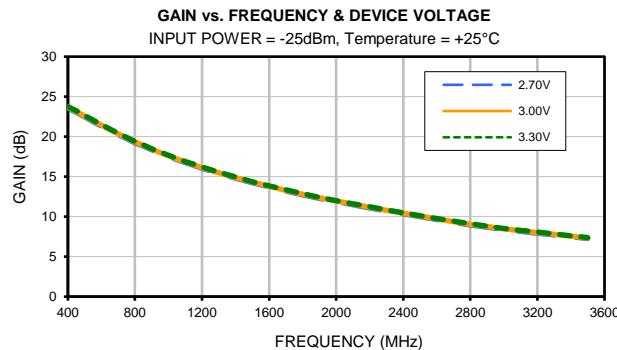
TEST CONDITIONS: Vd = 3.30V, Id = 65mA @Temperature = +25°C

FREQ. (MHz)	Gain (dB)	Isolation (dB)	Input Return Loss (dB)	Output Return Loss (dB)	Stability		IP-3 Output (dBm)	1dB Comp. Output (dBm)	Noise Figure (dB)
400	23.77	28.22	10.88	17.54	1.09	0.66	33.31	17.77	0.60
450	23.23	27.26	11.78	19.37	1.08	0.62	33.85	17.82	0.58
500	22.65	26.36	12.43	21.14	1.06	0.60	33.71	18.29	0.57
550	22.07	25.60	12.89	22.78	1.06	0.58	34.40	18.14	0.55
600	21.50	24.93	13.22	24.16	1.05	0.57	34.68	18.16	0.54
650	20.95	24.26	13.49	25.51	1.05	0.56	35.55	18.49	0.53
700	20.42	23.69	13.73	26.84	1.05	0.56	35.69	18.28	0.53
750	19.91	23.13	13.95	28.08	1.05	0.55	35.92	18.24	0.53
800	19.42	22.64	14.13	29.23	1.05	0.55	36.01	18.58	0.53
850	18.95	22.15	14.33	29.91	1.05	0.55	36.34	18.36	0.53
900	18.50	21.68	14.56	30.26	1.04	0.55	36.46	18.33	0.51
950	18.08	21.26	14.75	30.52	1.04	0.55	36.88	18.28	0.50
1000	17.67	20.84	14.97	30.57	1.05	0.55	37.28	17.99	0.50
1050	17.28	20.46	15.16	30.50	1.05	0.55	37.64	18.34	0.51
1100	16.90	20.09	15.42	30.06	1.05	0.55	37.11	17.98	0.53
1150	16.55	19.72	15.65	29.50	1.05	0.55	36.67	18.05	0.53
1200	16.20	19.39	15.90	28.99	1.05	0.55	36.13	18.66	0.55
1300	15.55	18.73	16.31	27.76	1.05	0.54	37.12	18.20	0.57
1400	14.95	18.15	16.83	26.89	1.05	0.54	37.38	18.42	0.59
1500	14.38	17.58	17.30	25.99	1.05	0.54	38.32	18.72	0.61
1600	13.86	17.07	17.80	25.56	1.05	0.54	37.72	18.28	0.61
1700	13.35	16.59	18.20	25.22	1.05	0.54	37.80	18.11	0.64
1800	12.87	16.12	18.65	25.05	1.05	0.54	37.49	18.41	0.64
1900	12.42	15.71	18.96	24.94	1.06	0.55	37.79	18.98	0.64
2000	12.01	15.29	19.14	24.84	1.06	0.55	38.07	18.59	0.64
2100	11.61	14.90	19.30	24.93	1.06	0.55	38.56	18.89	0.64
2200	11.23	14.54	19.28	25.21	1.06	0.55	38.21	19.00	0.65
2300	10.86	14.21	19.25	25.63	1.06	0.55	38.68	18.74	0.66
2400	10.49	13.88	19.31	25.77	1.06	0.56	37.96	18.51	0.67
2500	10.14	13.59	19.23	26.02	1.06	0.57	38.25	18.51	0.71
2600	9.78	13.32	19.32	25.92	1.07	0.57	39.46	19.06	0.78
2700	9.44	13.07	19.43	25.91	1.07	0.58	36.20	18.83	0.86
2800	9.11	12.83	19.73	25.25	1.08	0.59	36.82	19.05	0.92
2900	8.81	12.59	20.03	24.63	1.08	0.60	38.58	19.03	0.93
3000	8.54	12.33	20.30	23.55	1.08	0.60	39.88	19.08	0.93
3100	8.30	12.07	20.31	22.52	1.08	0.59	40.49	18.99	0.92
3200	8.07	11.80	20.25	21.58	1.07	0.59	41.60	18.88	0.93
3300	7.84	11.56	20.17	20.85	1.07	0.59	40.46	19.56	0.93
3400	7.62	11.34	19.95	20.04	1.07	0.59	40.38	19.71	0.95
3500	7.39	11.12	19.81	19.43	1.07	0.59	41.02	19.61	0.98

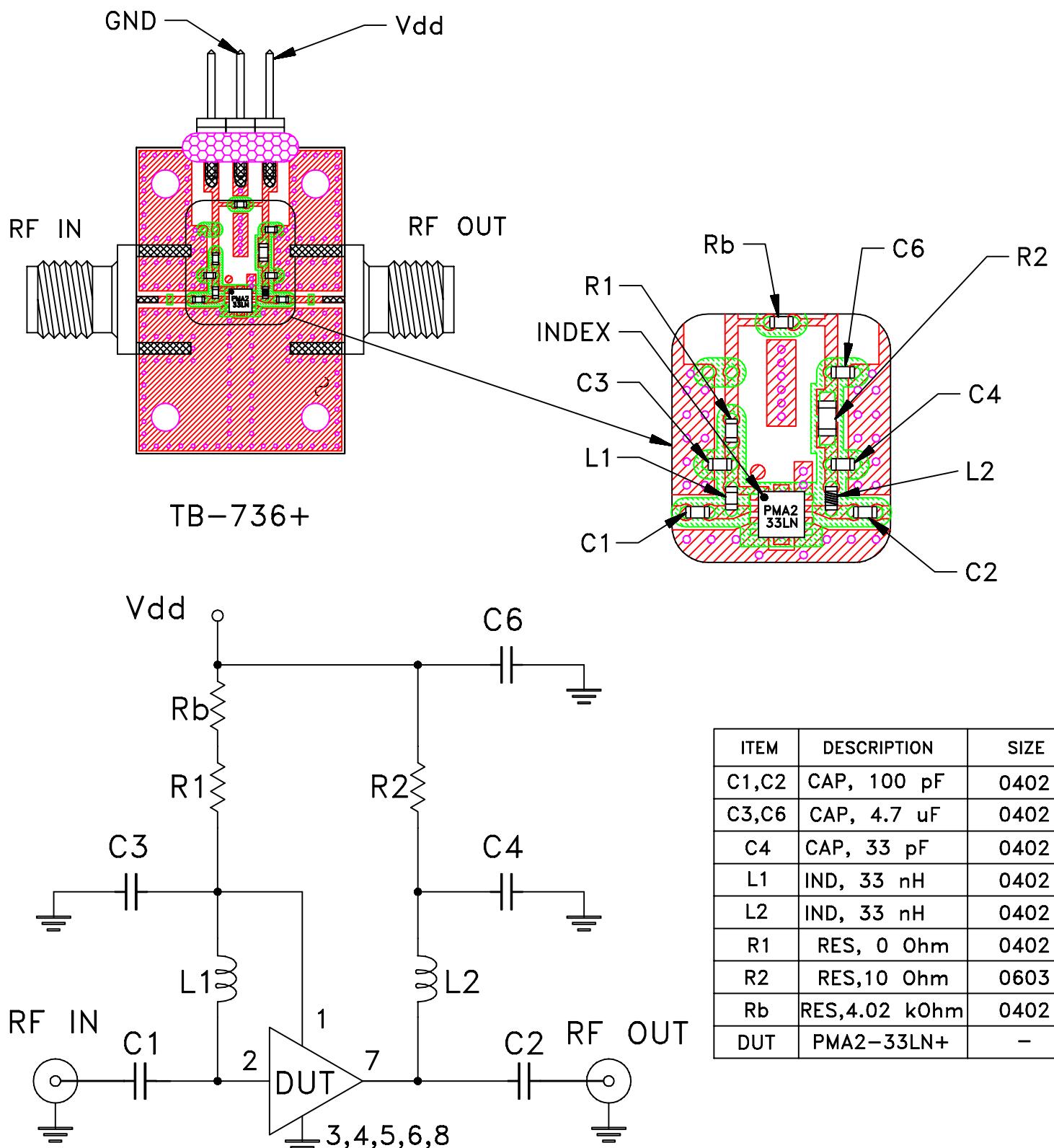
MMIC Amplifier Die

PMA2-33LN-D+

Typical Performance Curves



Evaluation Board and Circuit



Schematic Diagram

NOTES:

1. SMA Female connectors.
2. PCB material: Rogers RO4350 or equivalent,
dielectric constant=3.5,
dielectric thickness=.010 inch.

Mini-Circuits®



Environmental Specifications

ENV08T1

All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
Operating Temperature	-40° to 85°C or -45° to 85°C Ambient Environment	Individual Model Data Sheet
Storage Temperature	-55° to 100° C or -65° to 150° Ambient Environment	Individual Model Data Sheet
Thermal Shock	-55° to 100°C, 100 cycles	MIL-STD-202, Method 107, Condition A-3, except +100°C
Mechanical Shock	1.5Kg, 0.5 ms, 5 shock pulses, Y1 direction only	MIL-STD-883, Method 2002, Condition B, except Y1 direction only
Vibration (Variable Frequency)	50g peak	MIL-STD-883, Method 2007, Condition B
Autoclave	15 psig, 100% RH, 121°C, 96 hours	JESD22-A102, Condition C
HAST	130°C, 85% RH, 96 hours	JESD22-A110
Solderability	10X Magnification	J-STD-002, Para 4.2.5, Test S, 95% Coverage
Solder Reflow Heat	Sn-Pb Eutetic Process: 240°C peak Pb-Free Process: 260°C peak	J-STD-020, Table 4-1, 4-2 and 5-2; Figure 5-1
Moisture Sensitivity: Level 1	Bake at 125°C for 24 hours Soak at 85°C/85% RH for 168 hours, Reflow 3 cycles at 260°C peak	J-STD-020
Marking Resistance to Solvents	Isopropyl alcohol + mineral spirits at 25°C; terpene defluxer at 25°C; distilled water + propylene glycol monomethyl ether +	MIL-STD-202, Method 215



All Mini-Circuits products are manufactured under exacting quality assurance and control standards, and are capable of meeting published specifications after being subjected to any or all of the following physical and environmental test.

Specification	Test/Inspection Condition	Reference/Spec
	monoethanolamine at 63°C to 70°C	